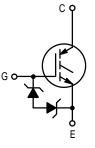
Product Preview Insulated Gate Bipolar Transistor N-Channel Enhancement-Mode Silicon Gate

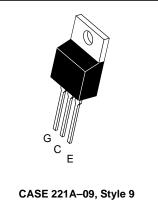
This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage–blocking capability. It also provides fast switching characteristics and results in efficient operation at high frequencies.

- Industry Standard TO-220 Package
- High Speed E_{off}: 67 μJ/A typical at 125°C
- Low On–Voltage 1.7 V typical at 10 A, 125°C
- Robust High Voltage Termination
- ESD Protection Gate–Emitter Zener Diodes



MGP20N60U

IGBT IN TO-220 20 A @ 90°C 31 A @ 25°C 600 VOLTS VERY LOW ON-VOLTAGE



TO-220AB

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit		
Collector–Emitter Voltage	VCES	600	Vdc		
Collector–Gate Voltage (R _{GE} = 1.0 MΩ)	VCGR	600	Vdc		
Gate-Emitter Voltage — Continuous	VGE	±20	Vdc		
Collector Current— Continuous @ $T_C = 25^{\circ}C$ — Continuous @ $T_C = 90^{\circ}C$ — Repetitive Pulsed Current (1)	IC25 IC90 IСМ	31 20 40	Adc Apk		
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	142 0.89	Watts W/°C		
Operating and Storage Junction Temperature Range	TJ, Tstg	-55 to 150	°C		
Thermal Resistance — Junction to Case – IGBT — Junction to Ambient	R _{θJC} R _{θJA}	1.12 65	°C/W		
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	200	°C		
Mounting Torque, 6–32 or M3 screw	10	10 lbf•in (1.13 N•m)			

(1) Pulse width is limited by maximum junction temperature. Repetitive rating.

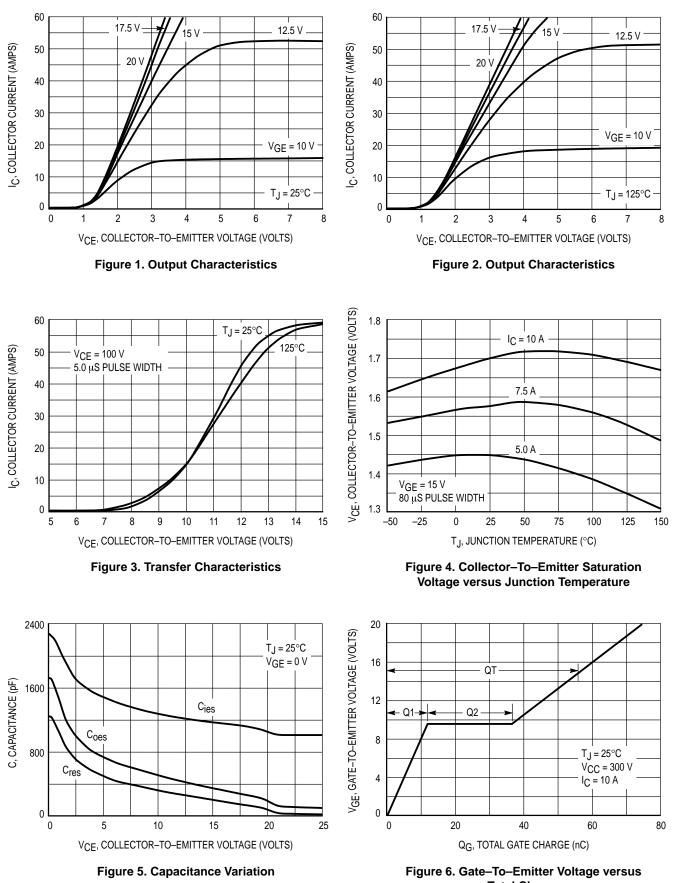
This document contains information on a new product. Specifications and information herein are subject to change without notice.



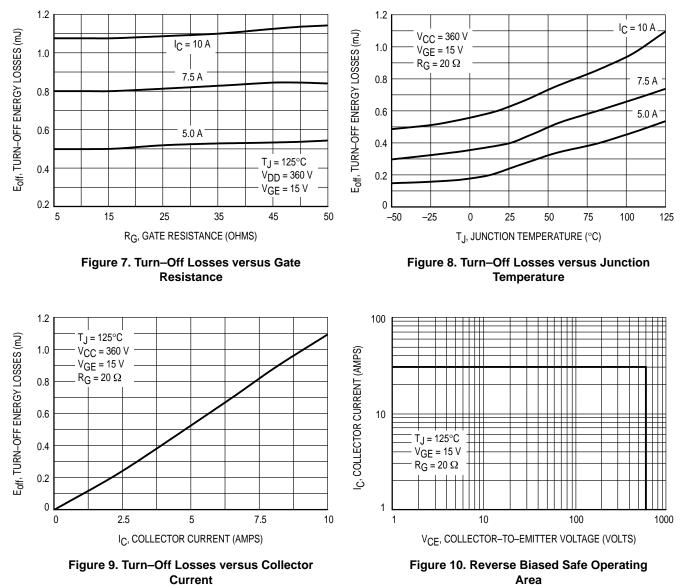
ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Cha	racteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•				
Collector–to–Emitter Breakdown Voltage (V _{GE} = 0 Vdc, I _C = 25 μ Adc) Temperature Coefficient (Positive)		V(BR)CES	600 —	 870	_	Vdc mV/°C
Emitter-to-Collector Breakdown Voltage (V _{GE} = 0 Vdc, I _{EC} = 100 mAdc)		V(BR)ECS	15	_	—	Vdc
Zero Gate Voltage Collector Current ($V_{CE} = 600 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}$) ($V_{CE} = 600 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}$)		ICES			10 200	μAdc
Gate–Body Leakage Current (V _{GE} = \pm 20 Vdc, V _{CE} = 0 Vdc)		IGES	—	_	50	μAdc
ON CHARACTERISTICS (1)						
$ Collector-to-Emitter On-State Volt \\ (V_{GE} = 15 Vdc, I_C = 5.0 Adc) \\ (V_{GE} = 15 Vdc, I_C = 5.0 Adc, T_J \\ (V_{GE} = 15 Vdc, I_C = 10 Adc, T_J) $	= 125°C)	VCE(on)	 	1.4 1.3 1.7	1.7 — 2.0	Vdc
Gate Threshold Voltage ($V_{CE} = V_{GE}$, $I_{C} = 1.0$ mAdc) Threshold Temperature Coefficie	nt (Negative)	VGE(th)	3.0 —	5.0 10	7.0	Vdc mV/°C
Forward Transconductance (V _{CE} =	= 10 Vdc, I _C = 10 Adc)	9fe	—	7.0	—	Mhos
OYNAMIC CHARACTERISTICS		•				
Input Capacitance	(V _{CE} = 25 Vdc, V _{GE} = 0 Vdc, f = 1.0 MHz)	C _{ies}	—	1060	—	pF
Output Capacitance		C _{oes}	—	99	—	
Transfer Capacitance		C _{res}	—	15	—	
SWITCHING CHARACTERISTICS (1)					
Turn-On Delay Time		^t d(on)	—	43	—	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_C = 10 \text{ Adc}, V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}, R_G = 20 \Omega, T_J = 25^{\circ}\text{C})$ Energy losses include "tail"	tr	—	45	—	
Turn-Off Delay Time		^t d(off)	—	144	—	
Fall Time		tf	—	175	—	
Turn–Off Switching Loss		E _{off}	—	340	—	μJ
Turn-On Delay Time	$(V_{CC} = 360 \text{ Vdc}, I_C = 10 \text{ Adc},$ $V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H},$ $R_G = 20 \Omega, T_J = 125^{\circ}\text{C})$ Energy losses include "tail"	^t d(on)	—	43	—	ns
Rise Time		tr	—	56	—	
Turn–Off Delay Time		^t d(off)	—	235	—	
Fall Time		t _f	_	220	_]
Turn–Off Switching Loss		E _{off}	—	625	—	μJ
Gate Charge	(V _{CC} = 360 Vdc, I _C = 10 Adc, V _{GE} = 15 Vdc)	QT	—	57	—	nC
		Q ₁	—	12	—	
		Q2	—	25	—	1
NTERNAL PACKAGE INDUCTANC	E					
Internal Emitter Inductance (Measured from the emitter lead 0.25" from package to emitter bond pad)		LE	_	7.5	_	nH

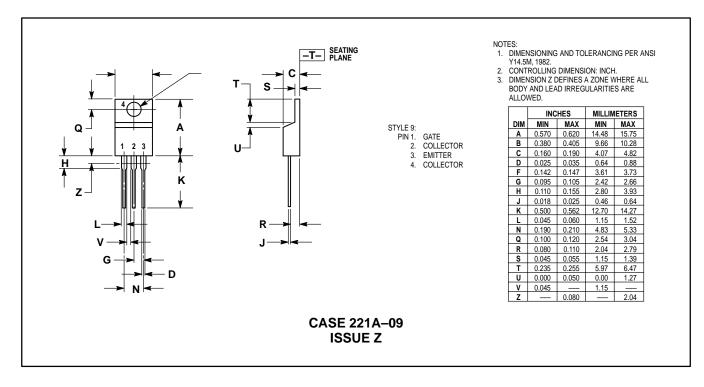
(1) Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.



Total Charge



PACKAGE DIMENSIONS



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ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 141,

4-32-1 Nishi-Gotanda, Shagawa-ku, Tokyo, Japan. 03-5487-8488

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